# MSKSEMI 美森科













**ESD** 

TVS

TSS

MOV

GDT

PLED

MSLM2904DT

**Product specification** 





#### **GENERAL DESCRIPTION**

The MSLM2904DT consists of two independent, high g ain and internally frequency compensated operational amplifiers, they are specifically designed to operate from a single power supply. Operation from split power supply is also possible and the low power supply current drain is independent of the magnitude of the power supply voltages. Typical applications include transducer amplifiers, DC gain blocks and most conventional operational amplifier circuits.

The MSLM2904DT is available in SOP-8 package.

### **FEATURES**

- Internally Frequency Compensated for Unity Gain
- Large Voltage Gain: 100dB (Typical)
- Low Input Bias Current: 20nA (Typical)
- Low Input Offset Voltage: 2mV (Typical)
- Low Supply Current: 0.5mA (Typical)
- Wide Power Supply Voltage: Single Supply: 3V to 36V

Dual Supplies: ±1.5V to ±18V

- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V to V<sub>CC</sub>-1.5V
- Lead-Free Packages: SOP-8

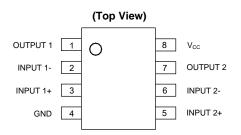
## **Applications**

- Battery Charger
- Cordless Telephone
- Switching Power Supply

## **Reference News**

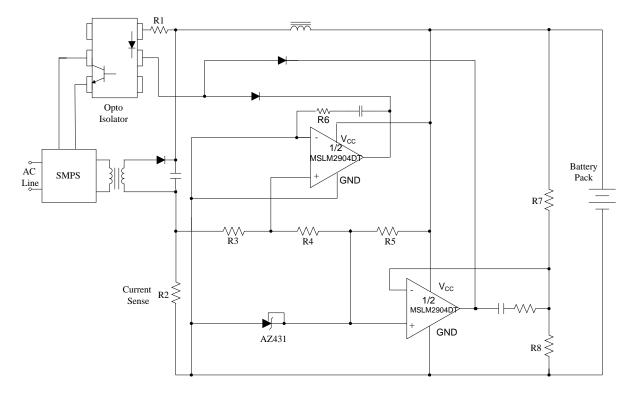
Type No	SOP-8	MARKING		
MSLM2904DT		MSKSEMI LM2904DT MS**		

# **Pin Assignments**

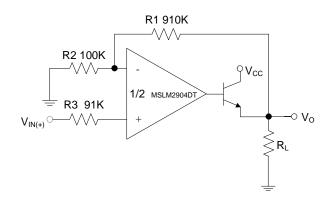


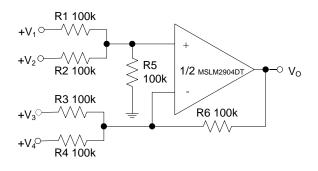


# **Typical Applications Circuit**



**Battery Charger** 



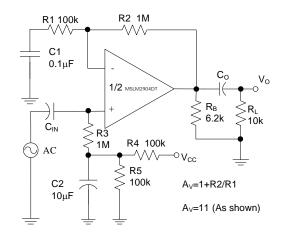


Power Amplifier

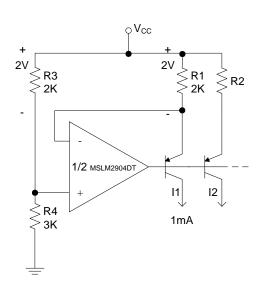
DC Summing Amplifier



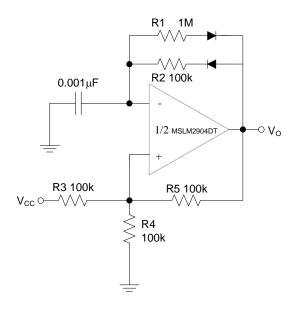
# **Typical Applications Circuit (Cont.)**



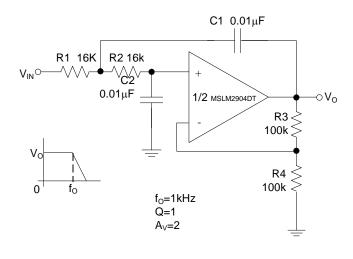
AC Coupled Non-Inverting Amplifier



**Fixed Current Sources** 



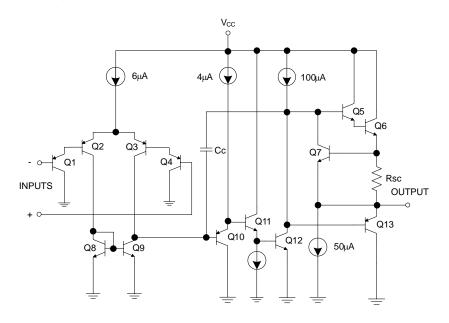
Pulse Generator



DC Coupled Low-Pass Active Filter



# **Functional Block Diagram**



## Absolute Maximum Ratings (Notes 1 & 2)

Symbol	Parameter	Rating	Unit
Vcc	Power Supply Voltage	40	V
VID	Differential Input Voltage	40	V
Vic	Input Voltage	-0.3 to 40	V
Po	Power Dissipation (T <sub>A</sub> = +25°C)	550	mW
TJ	Operating Junction Temperature	+150	°C
Тѕтс	Storage Temperature Range	-65 to +150	°C
TLEAD	Lead Temperature (Soldering, 10 Seconds)	+260	°C

Notes:

- 1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.
- 2. ESD sensitivity.

# **Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Unit
Vcc	Supply Voltage	3	36	V
Та	Ambient Operating Temperature Range	-40	+85	°C



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Vcc	Power Supply Voltage	40	V
VID	Differential Input Voltage	40	V
Vic	Input Voltage	-0.3 to 40	V
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Symbol	Parameter	Min	Max	Unit
Vcc	Supply Voltage	3	36	V
ТА	Ambient Operating Temperature Range	-40	+85	°C



Electrical Characteristics (Limits in standard typeface are for TA = +25°C, bold typeface applies over -40°C to +85°C (Note 6), V

Symbol	Parameter Conditions		Min	Тур	Max	Unit	
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	l		$V_0 = 1.4V$ , $R_S = 0\Omega$ , $V_{CC} = 5V$ to	_	2	5	mV
$V_{10}$	Input Offset Volta	age	30V	_		7	
ΔV10/ΔΤ	Average Temperature Coefficient of Input Offset Voltage		Coefficient of Input Offset		7	_	μV/°C
IBIAS	Input Bias Curre	nt	lin+ or lin-, Vcm = 0V	_	20	200	nA
IBIAS	mpat Blac Carro		IIIV OI IIIV-, V CIVI — O V			200	11/1
lio	Input Offset Curr	rent	IIN+ - IIN-, VCM = 0V	_	5	30	nA
			inv, voivi ov	_	_	100	11/ \
VIR	Input Common N (Note 2)	lode Voltage Range	Vcc = 30V	0	_	Vcc - 1.5	V
Icc	Supply Current		TA = -40°C to +85°C, RL = $\infty$ , Vcc = 30V	_	0.7	2	mA
	Supply Surrent		TA = -40°C to +85°C, RL = $\infty$ , Vcc = 5V	_	0.5	1.2	1117 (
Gv	Large Signal Vol	ge Signal Voltage Gain	Vcc = 15V, Vo = 1V to 11V, RL≥	85	100	_	dB
Gy Large orginal vol		9	2kΩ	80	_	_	
CMRR	Common Mode I	Rejection Ratio	DC, Vcm = 0V to (Vcc-1.5)V	60	70		dB
Civil (1) Continion Mode	rejection realio	DC, V CW = 0V to (VCC-1.5)V	60		_	uБ	
PSRR Power Supply Reject		eiection Ratio	Vcc = 5V to 30V	70	100		dB
			V CC = 3V 10 30V	60	_	_	
CS	Channel Separat	tion	f = 1kHz to 20kHz	_	-120	_	dB
Isource		Source	VIN+ = 1V, VIN- = 0V, VCC =	20	40	_	mA
			15V, Vo = 2V	20		_	
	Output Current		V <sub>IN</sub> + = 0V, V <sub>IN</sub> - = 1V, V <sub>CC</sub> =	10	15		mA
Isink		Sink	15V, Vo = 2V	5	_	_	
			V <sub>IN</sub> + = 0V, V <sub>IN</sub> - = 1V, V <sub>CC</sub> = 15V, V <sub>O</sub> = 0.2V	12	50	_	μΑ
Isc	Output Short Circuit Current to Ground		Vcc = 15V		40	60	mA
			$V_{CC} = 30V, R_L = 2k\Omega$	26			V
VoH Output \			$Vcc = 30V$ , $RL = 2k\Omega$ $Vcc = 30V$ , $RL = 10k\Omega$	26		_	
	Output Voltage S	Swing		27	28	_	
Output Voltage		willig	V CC COV, TEL TORS2	27		_	
Vol			$Vcc = 5V$ , $RL = 10k\Omega$	_	5	20	mV
			- ,			30	
θις	Thermal Resistance (Junction to Case)			_	17		°C/W
$\theta_{JA}$	Thermal Resistance (Junction to Ambient)				115		

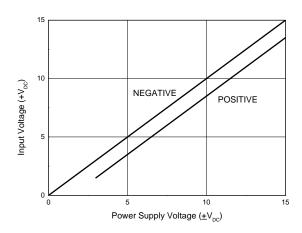
Notes: 1. Limits over the full temperature are guaranteed by design, but not tested in production.

<sup>2.</sup> The input common-mode voltage of either input signal voltage should not be allowed to go negatively by more than 0.3V (at +25°C). The upper end of the common-mode voltage range is Vcc-1.5V (at +25°C), but either or both inputs can go to +36V without damages, independent of the magnitude of the VCC.

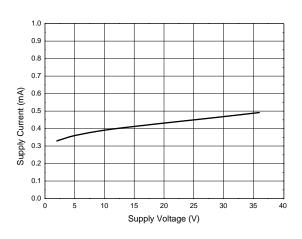


## **Performance Characteristics**

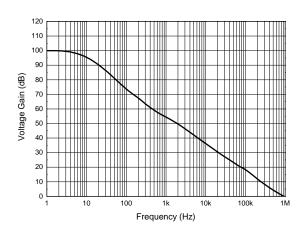
#### **Input Voltage Range**



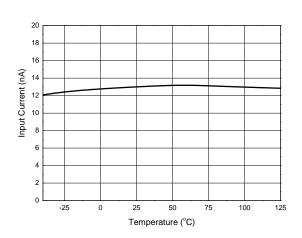
## **Supply Current**



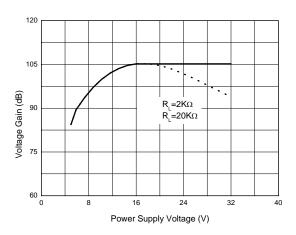
## **Open Loop Frequency Response**



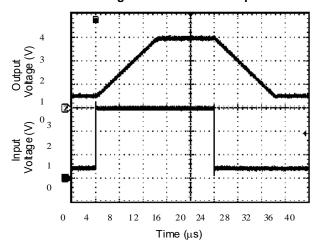
#### **Input Current**



#### Voltage Gain



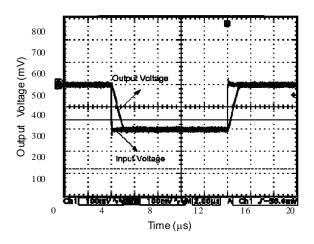
#### Voltage Follower Pulse Response



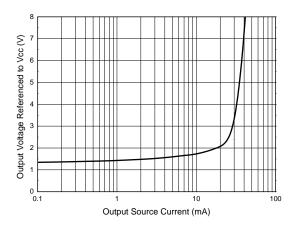


## **Performance Characteristics (Cont.)**

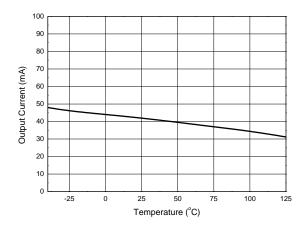
#### **Voltage Follower Pulse Response (Small Signal)**



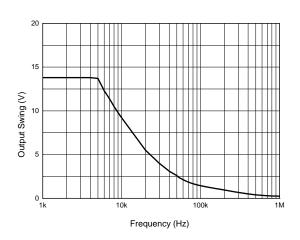
#### **Output Characteristics: Current Sourcing**



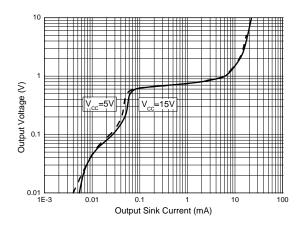
#### **Current Limiting**



#### **Large Signal Frequency Response**



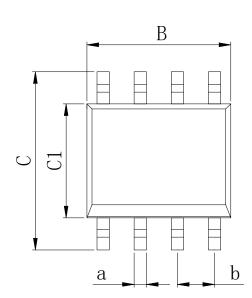
## **Output Characteristics: Current Sinking**

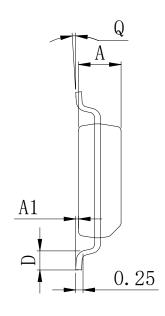




# **Physical Dimensions**

SOP-8





Dimensions In Millimeters(SOP-8)									
Symbol:	Α	A1	В	С	C1	D	Q	а	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	9 6.20	4.00	0.80	8°	0.45	1.27 BSC

# **ORDER INFORMATION**

P/N	PKG	QTY
MSLM2904DT	SOP-8	2500



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